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[Vishay Semiconductor/Diodes Division](#)
[VB40M120C-E3/8W](#)

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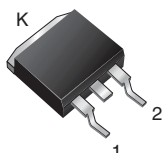
VB40M120C-E3

Vishay General Semiconductor

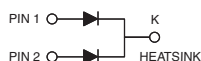
Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.46\text{ V}$ at $I_F = 5\text{ A}$

TMBS®
TO-263AB



VB40M120C



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 20 A
V_{RRM}	120 V
I_{FSM}	250 A
V_F at $I_F = 20\text{ A}$	0.64 V
T_J max.	150 °C
Package	TO-263AB
Diode variations	Common cathode

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VB40M120C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	120	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	40
		per diode	20
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	250	A
Voltage rate of change (rated V_R)	dV/dt	10 000	V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150	°C



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.54	-	V
	I _F = 10 A			0.64	-	
	I _F = 20 A			0.79	0.89	
	I _F = 5 A	T _A = 125 °C		0.46	-	
	I _F = 10 A			0.54	-	
	I _F = 20 A			0.64	0.72	
Reverse current per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	4	-	μA
		T _A = 125 °C		3	-	mA
	V _R = 120 V	T _A = 25 °C		-	500	μA
		T _A = 125 °C		6	32	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 20 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	VB40M120C	UNIT
Typical thermal resistance per diode	R _{θJC}	1.8	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VB40M120C-E3/4W	1.39	4W	50/tube	Tube
TO-263AB	VB40M120C-E3/8W	1.39	8W	800/reel	Tape and reel

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

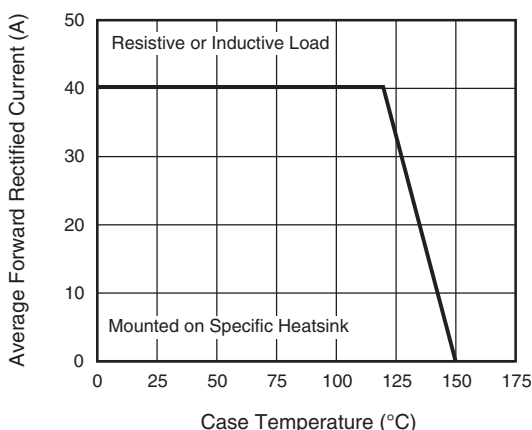


Fig. 1 - Maximum Forward Current Derating Curve

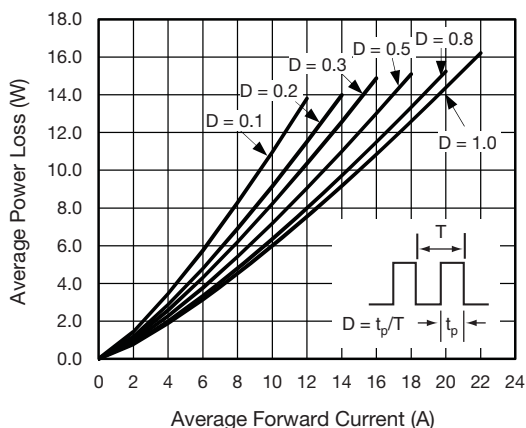


Fig. 2 - Forward Power Loss Characteristics Per Diode



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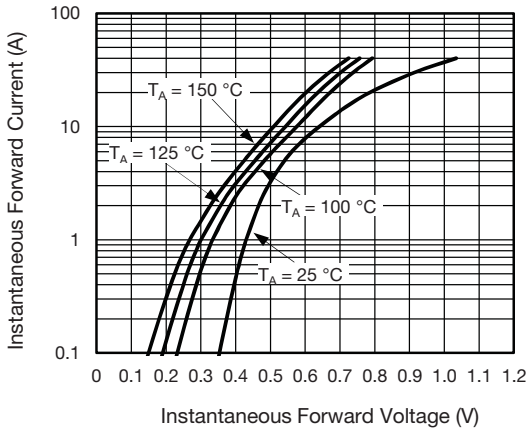


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

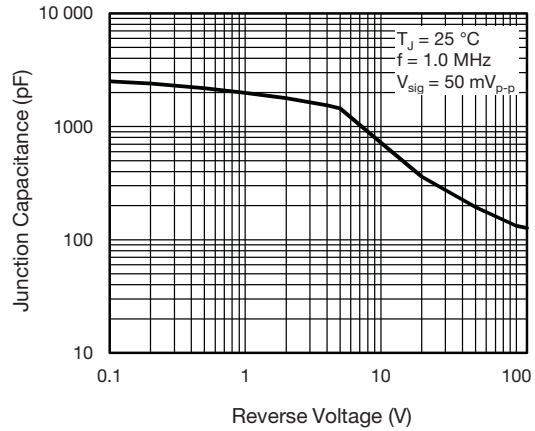


Fig. 5 - Typical Junction Capacitance Per Diode

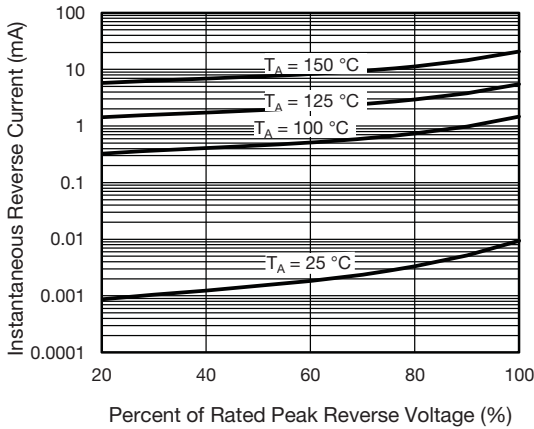


Fig. 4 - Typical Reverse Characteristics Per Diode

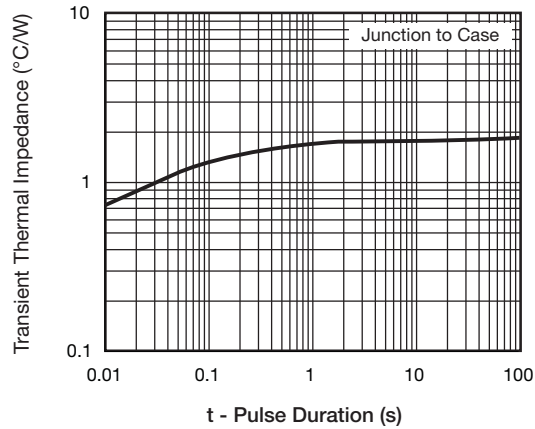
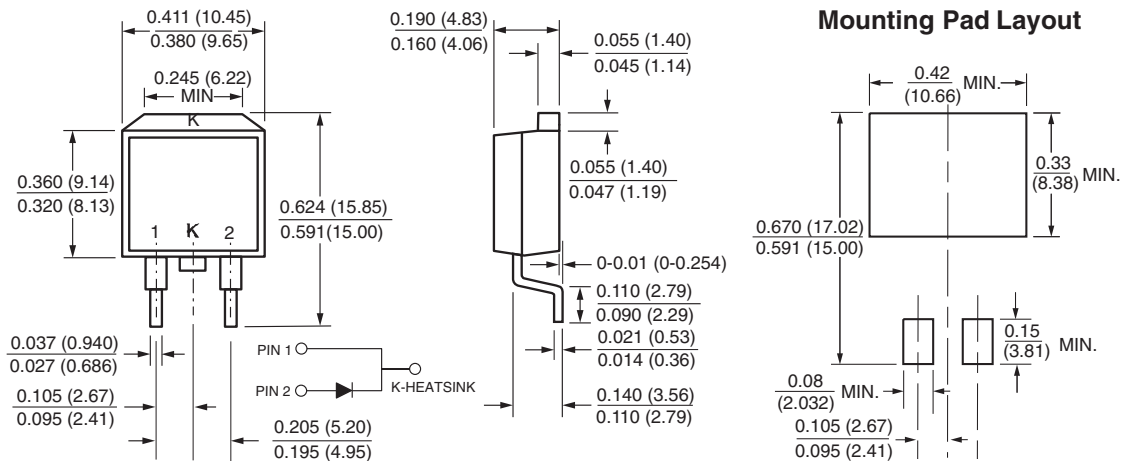


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB





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